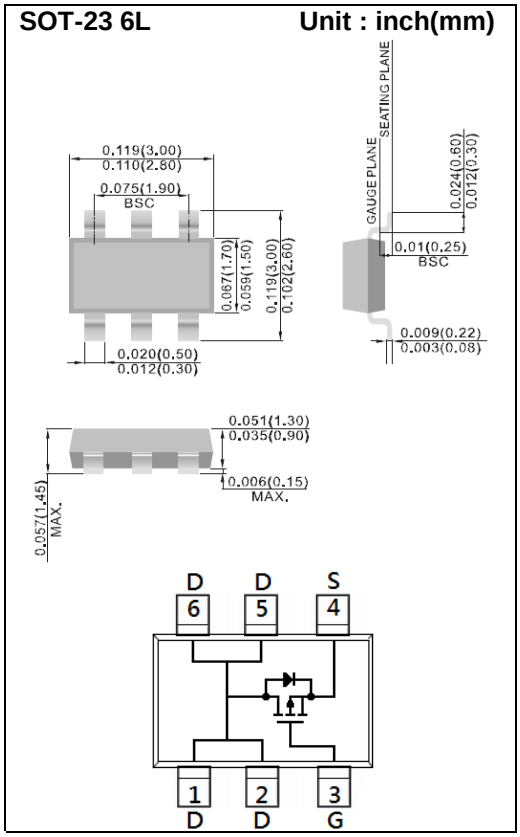
PJS6403

30V P-Channel Enhancement Mode MOSFET

Voltage	-30 V	Current	-6.4A



Features

- $R_{DS(ON)}$, V_{GS}@-10V, I_D@-4A<32mΩ
- $R_{DS(ON)}$, V_{GS}@-4.5V, I_D@-2A<46mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : SOT-23 6L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0005 ounces, 0.014 grams

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	-30	V
Gate-Source Voltage		V_{GS}	±20	
Continuous Drain Current (Note 4)		I_D	-6.4	A
Pulsed Drain Current (Note 1,3)		I_{DM}	-46	
Power Dissipation	T_a=25°C	P_D	2	W
	Derate above 25°C		16	mW/°C
Operating Junction and Storage Temperature Range		T_J,T_{STG}	-55~150	°C
Typical Thermal Resistance - Junction to Ambient (Note 5)		$R_{\theta JA}$	62.5	°C/W

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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V, I_D=-250uA	-30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=-250uA	-1	-1.6	-2.5	
Drain-Source On-State Resistance	$R_{DS(on)}$	V_{GS}=-10V, I_D=-4A	-	27	32	mΩ
		V_{GS}=-4.5V, I_D=-2A	-	38	46	
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=-30V, V_{GS}=0V	-	-	-1	uA
Gate-Source Leakage Current	I_{GSS}	V_{GS}=±20V, V_{DS}=0V	-	-	±100	nA
Dynamic (Note 6)						
Total Gate Charge	Q_g	V_{DS}=-15V, I_D=-5A, V_{GS}=-4.5V (Note 2,3)	-	7.8	-	nC
Gate-Source Charge	Q_{gs}		-	2.7	-	
Gate-Drain Charge	Q_{gd}		-	2.8	-	
Input Capacitance	Ciss	V_{DS}=-15V, V_{GS}=0V, f=1MHZ	-	870	-	pF
Output Capacitance	Coss		-	130	-	
Reverse Transfer Capacitance	Crss		-	93	-	
Turn-On Delay Time	$td_{(on)}$	V_{DD}=-15V, I_D=-1A, V_{GS}=-10V, R_G=6Ω (Note 2,3)	-	6.5	-	ns
Turn-On Rise Time	tr		-	8.8	-	
Turn-Off Delay Time	$td_{(off)}$		-	73	-	
Turn-Off Fall Time	tf		-	44	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	-2	A
Diode Forward Voltage	V_{SD}	I_S=-1A, V_{GS}=0V		-0.75	-1	V

NOTES :

1. Pulse width≤300us, Duty cycle≤2%.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
4. The maximum current rating is package limited.
5. $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 $inch^2$ with 2oz.square pad of copper.
6. Guaranteed by design, not subject to production testing

PJS6403

TYPICAL CHARACTERISTIC CURVES

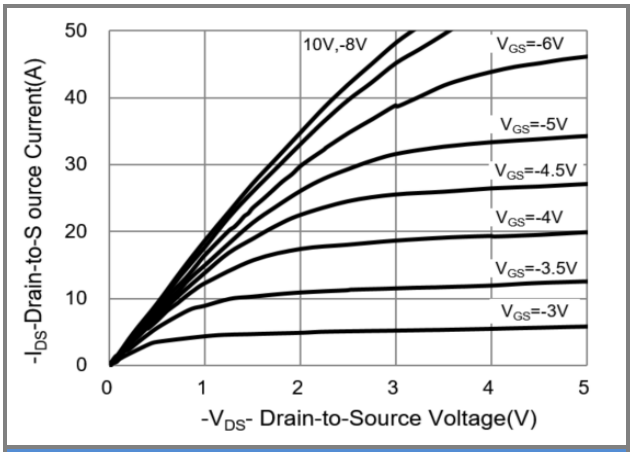


Fig.1 On-Region Characteristics

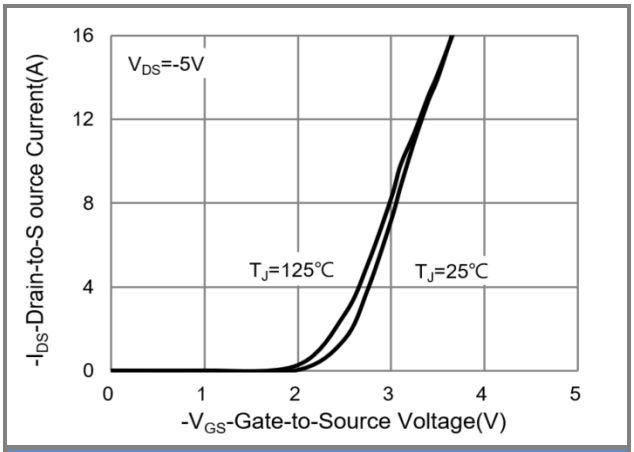


Fig.2 Transfer Characteristics

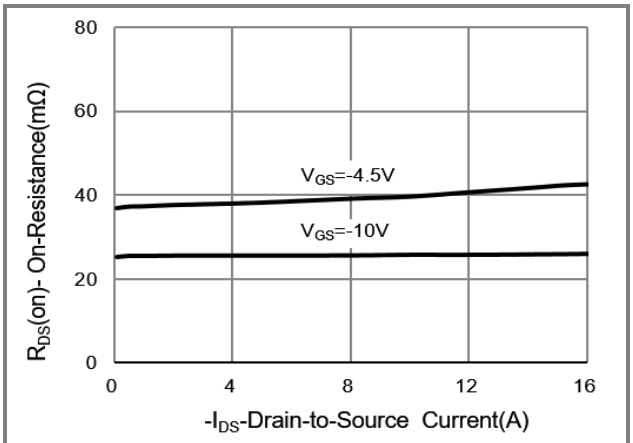


Fig.3 On-Resistance vs. Drain Current

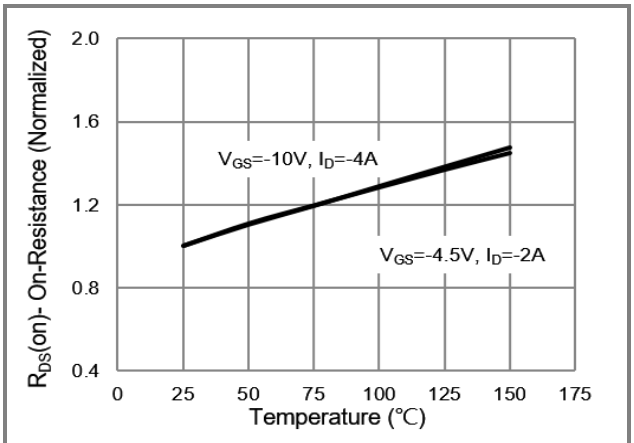


Fig.4 On-Resistance vs. Junction temperature

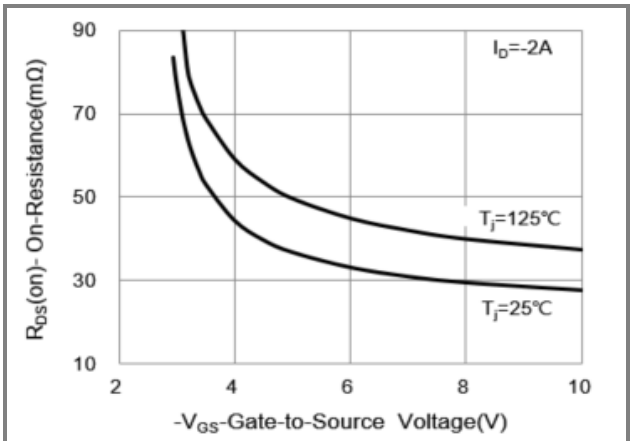


Fig.5 On-Resistance Variation with V_{GS}

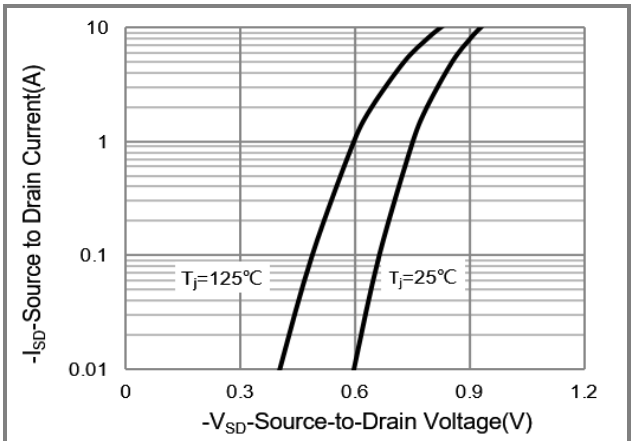


Fig.6 Body Diode Characteristics

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TYPICAL CHARACTERISTIC CURVES

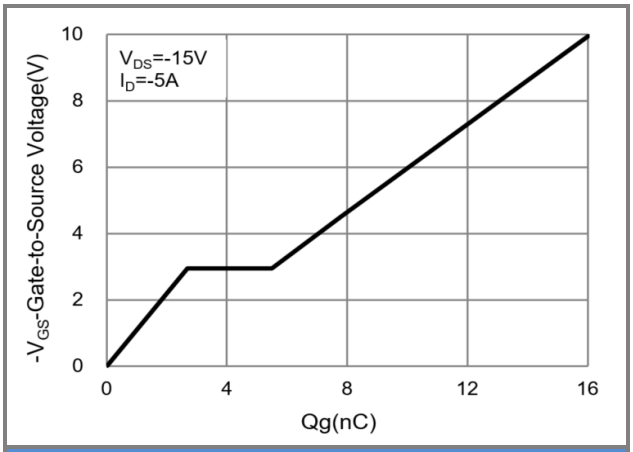


Fig.7 Gate-Charge Characteristics

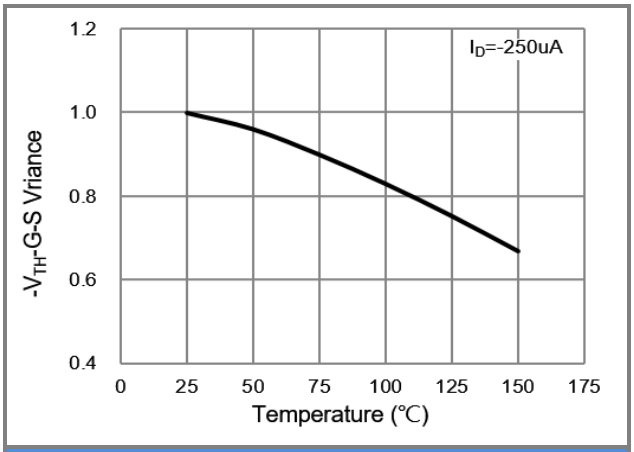


Fig.8 Threshold Voltage Variation with Temperature

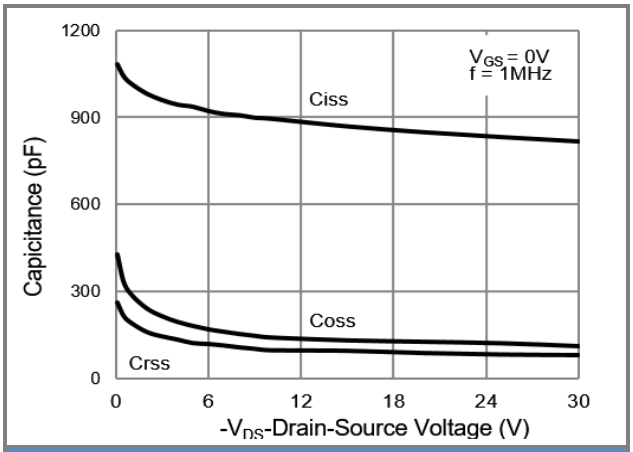


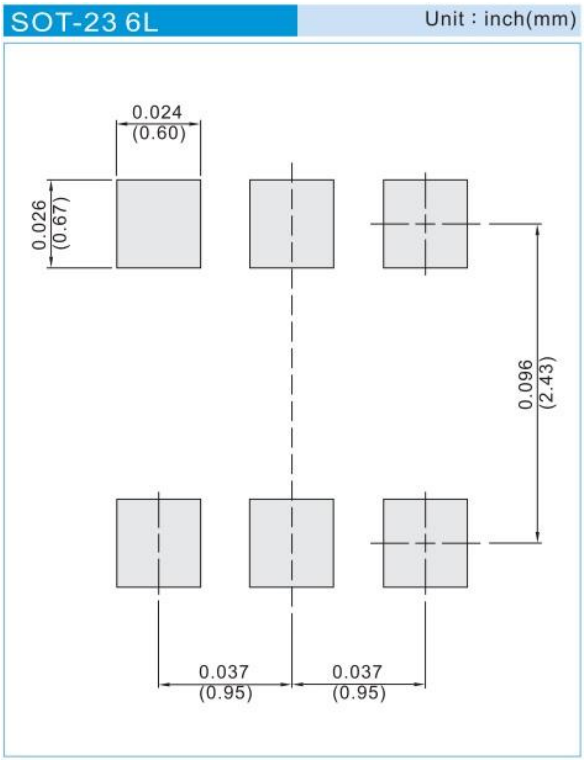
Fig.9 Capacitance vs. Drain-Source Voltage

PJS6403

Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJS6403_S1_00001	SOT-23 6L	3K pcs / 7” reel	S03	Halogen free

Mounting Pad Layout



PJS6403

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